

Full-scale chemical and field-effect passivation: 21.52% efficiency of stable MAPbI₃ solar cells via benzenamine modification

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ABSTRACT

Organic-inorganic metal halide perovskite solar cells have achieved high efficiency of 25.5%. Finding an effective means to suppress the formation of traps and correlate stability losses are thought to be a promising route for further increasing the photovoltaic performance and commercialization potential of perovskite photovoltaic devices. Herein, we report a facile passivation model, which uses a multi-functional organic molecule to simultaneously realize the chemical passivation and field-effect passivation for the perovskite film by an upgraded anti-solvent coating method, which reduces the trap states density of the perovskite, improves interface charge transfer, and thus promotes device performance. In addition, the hydrophobic groups of the molecules can form a moisture-repelling barrier on the perovskite grains, which apparently promotes the humidity stability of the solar cells. Therefore, the optimal power conversion efficiency (PCE) of perovskite solar cells after synergistic passivation reaches 21.52%, and it can still retain 95% of the original PCE when stored in ~ 40% humidity for 30 days. Our findings extend the scope for traps passivation to further promote both the photovoltaic performance and the stability of the perovskite solar cells.

KEYWORDS

chemical passivation, anti-solvent, MAPbl₃ solar cells, recombination, charge transfer

1 Introduction

Hybrid organic-inorganic perovskite solar cells (PSCs) are becoming a spotlight owing to their low-cost and high power conversion efficiencies (PCEs) for massive production [1–4]. A PCE of 25.5% has been reported by now [5], which is comparable to the commercialized silicon solar cells and become the auspicious photovoltaic devices. However, the defects on the surface and grain boundaries (GBs) of the as-prepared polycrystalline perovskite films are ready to be the site of nonradiative recombination for photo-excited charges [6–9]. The recombination limits the diffusion of carriers [10], reduces the minority carrier lifetime, and causes the ions migration and diffusion [11, 12], which in turn declines the PCEs and stability of PSCs. Hence, suppressing the non-radiative recombination at the perovskite surface and GBs is essential for achieving a high-performance and stable PSCs [13–15].

Currently, interface engineering and additive engineering are mainstream techniques for eliminating the defect states of the perovskite surface and enlarging the crystal size of perovskite to reduce recombination [14–19]. For example, the semiconductor molecule fullerene has been verified its advantages for passivating the trap states at GBs within the perovskite film. Because of the formation of fullerene-halide radicals, the Pb-I translocation defects within the perovskite films have been virtually eliminated [20-22]. Also, Huang et al. and Sargent et al. [23, 24] have inserted different types of insulting polymers as the ultrathin passivation layer into the perovskite/electron transport layer (ETL) hetero-interface to passivate the interfacial defects, thereby reduced the interfacial recombination losses and improved the device performance. White et al. [25, 26] adopted an ultrathin passivation layer consisting of poly(methyl methacrylate) and fullerene derivative mixture to passivate defects at the perovskite/TiO2 interface, significantly suppressing interfacial recombination; then, they reported a novel two-dimensional (2D)/three-dimensional (3D) PSCs using a mixed cation composition of 2D perovskite based on two different isomers of butylammonium iodide, enabling an high efficiency of 23.27%. You et al. [27] reported the using of an organic halide salt phenethylammonium iodide (PEAI) on perovskite films for surface passivation, which enables a high certificated efficiency of 23.32%. Previously, we have proposed an iodine-assisted upgraded anti-solvent strategy to control the crystallization and passivate the traps of perovskite, which also improves the PCE and long-term stability of solar cells [4]. The ultimate goal of these strategies can be summed up as "chemical passivation (CP)", which is intentionally constructing chemical bond (hydrogen bond, ionic bond, coordination bond, etc.) between

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perovskite traps and the external active agents, thus reducing the photo-excited charge recombination. While the molecular for CP must be exquisitely designed to eliminate the extra series resistance and charge transfer barrier, otherwise it will degrade the performance of the devices.

In retrospect, field-effect passivation (FEP), which has been successfully implemented on silicon solar cells, is another ingenious passivation strategy [28–32]. It establishes strong interfacial dipoles by covering a dielectric film on photo-absorber surface, which aims to selectively repel one charge (electron/hole) and attract another charge (hole/electron). That is to say, the FEP can decline the probability of photo-excited electron/hole recombination even without forming an extra chemical bond, thereby alleviating interface recombination and enhancing charge transfer. Accordingly, it is meaningful and crucial to developing the suitable passivation materials that can simultaneously provide the function of CP and FEP on PSCs, and revealing the corresponding operation mechanism in details.

For PSCs application, the ideal passivation materials that can achieve both FEP and CP should have appropriate chemical ligands to terminate the traps and a fixed majority carrier concentration to form the interface dipoles. In line with these requirements and our previous experiences, we found that a small semiconductor molecule, 4,4-cyclohexylidenebis[N,Nbis(4-methylphenyl)benzenamine] (TAPC) may be a potential alternative to achieve full-scale passivation for PSCs. The lone pair electrons of N atom in TAPC could chemically passivate Pb²⁺ defects within the perovskite film. Also, Yu et al. and Yang et al. [33, 34] reported that TAPC as archetypical p-type materials can provide FEP in silicon solar cells, which is beneficial to reducing interface recombination and boost charge transfer.

Based on the above research background, we proposed a universal and straightforward approach to introduce the TAPC into MAPbI₃ through a one-step anti-solvent method. This method judiciously combines the application of CP and FEP in the perovskite film, hence successfully reducing the interface recombination loss and enhancing the hole extraction. As an additional benefit, we found the $-CH_3$ tails of TAPC can form a moisture-repelling barrier on the MAPbI₃ grains, thereby improving the stability of the device in a humid environment. The operation mechanism of charge transfers kinetic, interfacial passivation, and device performance has been interpreted in detail. Ultimately, a high PCE of 21.52% in mesoscopic n-i-p MAPbI₃ solar cells is achieved. In room temperature, the cells degrade only \sim 5% after 30 days of exposure in 40% relative humidity.

2 Experimental section

Fabrication of MAPbI₃: 163 mg of MAI and 462 mg of PbI₂ were mixed in solvent of dimethylformamide (DMF) and dimethyl sulfoxide (DMSO) (v:v = 7:3) as the perovskite precursor. 5.5 mg of TAPC was dissolved in the 1 mL chlorobenzene (CB) solution as an upgraded anti-solvent. The precursor solution of perovskite was spin-coated onto the mesoporous TiO₂ layer at 4,000 rpm. During this process, 300 µL CB or upgraded anti-solvent was dripped at the beginning 30 s. Then, the obtained film was annealed at 60 °C for 5 min and 100 °C for 10 min to form the perovskite film. The entire perovskite film is prepared in a nitrogen glove box.

The detailed information regarding to the materials, the preparation of PSCs, and the corresponding characterization were provided in the Electronic Supplementary Material (ESM) as Supplementary Notes 1, 2 and 3, respectively.

3 Results and discussion

First, we studied the molecular structure and film properties of TAPC. TAPC is constructed by two tri(p-tolyl) amine (TTA) molecules chemically bridged by a cyclohexane ring (Fig. 1(a)) [35]. The molecular surface potential diagram of TAPC has obvious densely distributed areas of electron clouds (Fig. 1(b)), which are potential sites that can provide electrons. In addition, the -CH₃ group of the TAPC enables the molecule to be hydrophobic, which can be confirmed the water contact angle test (Fig. 1(c)). Figure S1 in the ESM shows the absorption and PL spectrum of TAPC film. The PL spectrum shows noticeable shoulders in the asymmetric 500 nm center band, which is due to the different configurations of adjacent molecular species that form excimers on crystal defects [36]. Figure S2 in the ESM shows the Fourier transform infrared (FTIR) spectrum of TAPC powder. Consistent with previous reports, the absorption bands at 1,505, 1,602, and 2,937 cm⁻¹ are ascribed to the C-N stretch, the para-aromatic ring stretch, and N-H stretch, respectively [37, 38]. The peaks at $3,000-3,200 \text{ cm}^{-1}$ come from the aromatic C-H stretch. The abundant chemical bonds



Figure 1 Analyze the properties of TAPC and demonstrating the enhancement of perovskite crystallization caused by TAPC. (a) The molecular structure of TAPC. (b) The molecular surface potential of TAPC. (c) The water contact angle test of TAPC film. (d) The *I*-*V* characters of the devices with a structure of Ag/TAPC/FTO (red) and Ag/TAPC/TiO₂/FTO (black), respectively. (e) XRD intensity of the control and MAPbI₃-TAPC films. SEM images of (f) control and (g) MAPbI₃-TAPC films.

TSINGHUA UNIVERSITY PRESS Springer | www.editorialmanager.com/nare/default.asp provide variety of choices for passivating perovskite. We used the current-voltage (I-V) test with a setup of Ag/TAPC/FTO and Ag/TAPC/TiO₂/FTO to evaluate the electrical performance of TAPC (Fig. 1(d)). Compared with the *I*-*V* curve of the single TAPC layer, the I-V curve of the TAPC/TiO₂ shows obvious rectification character, which proves the p-type nature of TAPC layer. In this study, we dissolved TAPC in CB as an upgraded anti-solvent for preparing the MAPbI₃ films. The X-ray diffraction (XRD) and scanning electron microscope (SEM) were performed to investigate the influence of TAPC on the morphology and crystal structure of the MAPbI₃ films. The XRD patterns of the perovskite films before and after the TAPC treatment are shown in Fig. 1(e). Two typical major diffraction peaks at ~ 14.4° and 28.8° could be indexed as (110) and (220) crystal plane of the MAPbI₃, which is agreed with previously report [39]. However, the TAPC-treated MAPbI₃ film (MAPbI₃-TAPC) demonstrates stronger reflective diffraction intensity than the control film (Table S1 in the ESM), indicating a better crystallinity. Moreover, the (110)/(310) peak ratio was improved from 5.71 to 8.13 after TAPC treatment, implying the TAPC treatment improved the preferred orientation of the perovskite films. The SEM images (Figs. 1(f) and 1(g)) also show that the crystal size of the MAPbI₃-TAPC film is larger and more uniform than that of the control film (the reason will be revealed in the following context). The size distribution of the control film and the MAPbI₃-TAPC film is shown in Fig. S3 in the ESM. One can see that the grains size of MAPbI₃-TAPC film is ~ 100 nm larger than that of the control film. The MAPbI₃-TAPC film also has stronger light absorption than the control film due to the improved crystallization, which can be observed from the images and absorbance spectra in Fig. S4 in the ESM.

Generally, good surface morphology and crystallinity of the film will reduce the grain boundary density where most defects are located. We further used the time-resolved photoluminescence (TRPL) spectroscopy to detect the non-radiative recombination within the perovskite films (Fig. 2(a) and Table S2 in the ESM). For the Glass/sample (control or MAPbI₃-TAPC) setup, the MAPbI₃-TAPC film exhibits a longer decay time, which indicates the traps-induced non-radiative recombination has been suppressed by the passivation of TAPC. Furthermore, the space-charge-limited-current (SCLC) test on a hole-only device with an architecture of FTO/PEDOT: PSS/perovskite/ spiro-OMeTAD/Ag was taken to study the trap density (N_{trap}) of the perovskite film (Fig. 2(b)). The device structure diagram and the calculation of N_{trap} are demonstrated in (Fig. S5 in the ESM). The N_{trap} of the MAPbI₃-TAPC was 3.18×10^{15} cm⁻³, which is lower than that of the control film $(1.04 \times 10^{16} \text{ cm}^{-3})$. In addition, Urbach absorption has also been performed to detect the band-tail states of the perovskite films, which is considered as a valuable parameter indicating the effects of all possible defects [40]. As shown in Fig. 2(c), the Urbach energy (E_u) value of MAPbI₃-TAPC film (29.34 meV) is lower than that of the control film (54.17 meV), which also indicates that the N_{trap} of MAPbI₃-TAPC film is reduced. The FTIR as well as the X-ray photoelectron spectroscopy (XPS) was performed to reveal the passivation details. The FTIR spectroscopy shows that the N-H bend of perovskite redshift from 1,464 to 1,468 cm⁻¹, and the N-H bond strength redshift from 3,102 to 3,116 cm⁻¹ (Fig. 2(d) and Fig. S6 in the ESM). Moreover, compared with the control film, the XPS patterns of both Pb 4f and I 3d core signals of MAPbI₃-TAPC shift slightly towards the lower binding energies (Figs. 2(e) and 2(f)). Some researchers have proposed that the interaction between passivation agents and perovskite could change the bond vibration and Pb 4f binding energy of the perovskite [41-44]. Therefore, as depicted in Fig. 2(g), the reduction of trap states in the MAPbI₃-TAPC film can be ascribed to the interaction between the MAPbI₃ and TAPC, which mainly occurs via passivates the Pb²⁺ dangling bonds by the N of TAPC (Fig. 2(g)) [6]. In addition, due to the interaction



Figure 2 CP-induced trap states elimination in MAPbI₃ film. (a) The TRPL spectra for the control and MAPbI₃-TAPC films, respectively. (b) The SCLC curves and (c) E_u value of the corresponding sample. (d) FTIR spectrum of the corresponding sample; XPS core level peaks of Pb 4f and I 3d of the (e) MAPbI₃ and (f) MAPbI₃-TAPC. (g) Schematic diagram of chemical passivation induced by TAPC incorporation.

between TAPC and Pb²⁺, the crystallization process is inevitably retarded, which is similar to previous findings [41, 42]. The slow crystallization process is conducive to enlarging the grain size and can be observed in Figs. 1(f) and 1(g).

In addition to chemical passivation, TAPC as an archetypical p-type molecule has a certain impact on the interfacial electric field, which in turn affects the charge transport. As shown in Fig. S7 in the ESM, TAPC has a bandgap of 3.5 eV and a Fermi level of 5.1 eV. Compared with the of MAPbI₃ (work function ~ 4.6 eV), the work function difference between MAPbI₃ and TAPC will inevitably cause the charge migration, resulting in interfacial dipoles (Fig. 3(a)). Similarly, we have observed this phenomenon at MoO_x/Si interface [45, 46]. This interfacial polarization can efficiently separate photo-generated carriers and reduce the probability of Shockley-Read-Hall (SRH) recombination [47], thus act as an FEP in PSCs. To visualize the origination of FEP on the perovskite film, we used scanning Kelvin probe microscopy (SKPM) to show the surface potential change. The experimental setup is demonstrated in Fig. 3(b). The results show that a ~ 55 mV of positive surface potential is changed when the probe is sweeping from the control film to the MAPbI₃-TAPC film (Figs. 3(c) and 3(d)). In addition, the surface potential of MAPbI3-TAPC film is more uniform than that of the control film (Fig. S8 in the ESM). As reported by Cao et al. [48], this phenomenon means a microscopic electric dipole moment with the positive charge end pointing toward the active layer (perovskite film) and the negative charge end pointing toward the modification layer (TAPC), which is conducive to extracting holes and repelling electrons (Fig. 3(a)) [49]. In order to further confirm the enhanced interfacial charge transport at MAPbI₃-TAPC/Spiro-OMeTAD interface, we conducted another TRPL test (Fig. 3(d)). The decay based on Glass/MAPbI₃-TAPC/HTL is faster than that of Glass/control/ HTL, which indicates that the TAPC interlayer promotes hole



Figure 3 TAPC-induced FEP improves charge transfer at the heterointerface. (a) Schematic diagram of interface polarization formed by TAPC passivation. (b) The setup for SKPM measurement. (c) The SKPM images of the sample. Region 1: The active layer (MAPbI₃). Region 2: The TAPC covered MAPbI₃. (d) The TRPL spectra and (e) $C^{-2}-V$ curves of the corresponding devices.

extraction. Furthermore, through the $C^{-2}-V$ curve, we found that the Fermi level difference (V_{bi}) of the MAPbI₃-TAPC device is 1.08 V, which is indeed higher than that of the control device (0.99 V) (Fig. 3(e)). The enhanced V_{bi} is beneficial to efficiently collect holes and repel electrons at the hetero-interface, thereby reducing the interfacial recombination and enhancing the photovoltaic performance. These results demonstrate that the TAPC can not only reduces the traps states of MAPbI₃ films by CP, but also improves the interface charge transfer through FEP, which is expected to improve the overall performance of the PSCs.

We further fabricated the n-i-p PSCs (FTO/m-TiO₂/ perovskite/Spiro-OMeTAD/Ag), as shown in Figs. 4(a) and 4(b). Figure 4(c) shows the J-V curves of the champion PSCs measured under both forward and reverse scan. The output parameters of the PSCs are shown in Table 1. The PCE of the control device obtained from the forward- and reverse-scan were 17.95% and 19.62% respectively, which is a typical PCE for MAPbI₃ solar cells. Consistent with the previous reports [50], the control device shows clear hysteresis due to the recombination-induced interfacial capacitance effect. For the MAPbI₃-TAPC devices, we have optimized the TAPC concentration and found that the 5.5 mg/mL is suitable for PSCs application (Fig. S9 in the ESM). For the champion MAPbI₃-TAPC cell, the reverse scan of FF is 80.26%, V_{oc} is 1.17 V, J_{sc} is 22.92 mA·cm⁻², and overall PCE is 21.52%. The PCE for forward scan is 21.08% (FF = 79.74%, V_{oc} = 1.16 V, $J_{\rm sc} = 22.79 \text{ mA} \cdot \text{cm}^{-2}$). The reduced J - V hysteresis and improved PCE can be ascribed to the synergy of CP and FEP, which simultaneously reduces the interface recombination and enhances the carrier transport. Figure 4(d) exhibits the external quantum efficiency (EQE) spectra of the PSCs. The MAPbI3-TAPC device shows a higher spectrum response in the long wavelength region than the control device. We further characterized open-circuit photovoltage decay (OCVD) of the devices to confirm the enhanced performance of the devices [51]. As shown in Fig. 4(e), the OCVD time of the MAPbI₃-TAPC device is longer than that of the control device, suggesting that the recombination losses within MAPbI₃-TAPC device are suppressed. This result is in line with the enhanced V_{oc} in the MAPbI₃-TAPC devices. The electrochemical impedance spectroscopy (EIS) measurements were used to further elucidate the internal electrical properties of the PSCs. The Nyquist plot with the frequency range of 100 Hz to 1 MHz measured is shown in Fig. 4(f) and Table S3 in the ESM. We found a marked drop in charge transfer recombination resistance (R_{tr}) and an increase in recombination resistance (R_{rec}) , which suggests an enhanced interface contact and suppressed charge recombination after incorporating the TAPC interlayer.

Except for the photovoltaic performance enhancement, since the -CH₃ of TAPC is a hydrophobic group, the contact angle of water of the MAPbI3-TAPC film is increased (Figs. 5(a) and 5(b), which is conducive to improving the stability of the PSCs [52-55]. This can be verified by the XRD patterns of the perovskite films after aging for 30 days (Fig. 5(c)). The control film shows a slight PbI₂ peak at 12.4° after aging, while the MAPbI₃-TAPC film still keeps a well-maintained crystal structure without observable PbI₂ peak. We further evaluated the repeatability and long-term stability of the solar cells. The statistical distribution of efficiency based on 50 devices suggested the reliability and repeatability of the MAPbI₃-TAPC devices are better than that of the control devices (Fig. 5(d)). The steady-state PCE with a bias voltage at the maximum power point (V_{mpp}) was measured to confirm the operation output. As shown in Fig. 5(e), the steady-state PCE of the champion



Figure 4 Device performance. (a) The schematic structure and (b) the cross-section of the device. (c) The illuminated *J*–*V* curves of the PSCs under forward- and reverse-scan, respectively. (d) The EQE, (e) OCVD, and (f) Nyquist plot of PSCs. The hollow square and dash line in (f) is the test data and the fitted data, respectively.

 Table 1
 The output parameters of the PSCs based on control and MAPbI3-TAPC under different scanning direction

| Device | | $J_{\rm sc}$ (mA·cm ⁻²) | V _{oc} (V) | FF (%) | PCE (%) |
|--------------------------|-----|-------------------------------------|------------------------|-----------|------------|
| Control | R–S | 22.18 | 1.15 | 76.91 | 19.62 |
| | F–S | 21.56 | 1.13 | 73.68 | 17.95 |
| MAPbI ₃ -TAPC | R–S | 22.92 | 1.17 | 80.26 | 21.52 |
| | F–S | 22.79 | 1.16 | 79.74 | 21.08 |



Figure 5 Stability of the devices. The water contact angle of (a) the control and (b) the MAPbI₃-TAPC films. (c) The XRD patterns of the control and MAPbI₃-TAPC films. (d) The PCEs distribution collected from 50 PSCs. (e) The output photocurrent extracted from the *V*_{mpp} bias of corresponding devices. (f) The normalized PCEs decay of the PSCs based on control and MAPbI₃-TAPC samples.

devices based on control and MAPbI₃-TAPC films are 18.09% and 21.10%, respectively. Figure 5(f) shows the normalized PCE against periodical time. As expected, the MAPbI₃-TAPC PSCs show enhanced ambient stability compare to the control ones. Exposing the PSCs under the environment with 40% humidity for 30-days, the MAPbI₃-TAPC device retained 95% of the initial PCE. We have studied the operational stability of the PSCs under MPP tracking with continuous light irradiation a N_2 atmosphere (Fig. S10 in the ESM). The control cell (MAPbI₃) shows a rapid loss of PCE (down to 81% of the initial PCE after irradiated 100 h), and the MAPbI₃-TAPC cell presents a better long-term stability, keeping more than 92% of original PCE after 100 h irradiation. This further verifies that the full-scale passivation brought by incorporating TAPC remarkably enhances the long-term stability of the PSCs.

4 Conclusions and perspectives

In conclusion, the photovoltaic performance of PSCs has been promoted by processing perovskite films with multi-functional organic molecule to simultaneously achieve the CP and FEP. It was proved that in the PSCs with n-i-p structure, the concerted passivation induced by TAPC molecules onto the perovskite film can both passivate the trap states and effectively extract holes. In contrast to the control device, the PCE of the MAPbI₃-TAPC device enhanced from 19.62% to 21.52%, and stability was significantly improved. In addition, the -CH₃ groups of TAPC molecule forms a moisture-repelling barrier on the MAPbI₃ particles, which significantly enhances the humidity stability of the film. The MAPbI₃-TAPC device keeps 95% of the initial PCE when stored for 30 days under 40% humidity. For the long-term perspective, it demonstrates that TAPC molecules can be a multifunctional alternative for passivating the perovskite. To further promote the photovoltaic performance of PSCs, we should take care of the FEP at the opposite ETL/perovskite interface by incorporating low work function interlayer, which can form bifacial FEP in PSCs. Ultimately, considering the recombination dynamic and defects-induced ion migration, we believe that the passivation of defects and effective charge extraction at the interface are key factors for further high performance and stable PSCs. For the foreseeable future, combining CP and FEP will synchronously terminate the active traps and enhance the interface charge transfer, hence triggering another routine for boosting the photovoltaic performance of the device.

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